

Features

- Trench Power MV MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

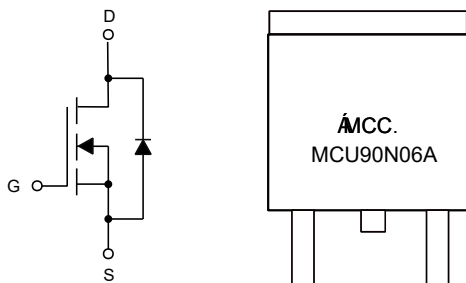
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 1.14°C/W Junction to Case
- Thermal Resistance: 20°C/W Junction to Ambient

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	90	A
Pulsed Drain Current ⁽¹⁾	I_{DM}	300	A
Total Power Dissipation ⁽²⁾	P_D	110	W
Single Pulsed Avalanche Energy ⁽³⁾	E_{AS}	196	mJ

Note:

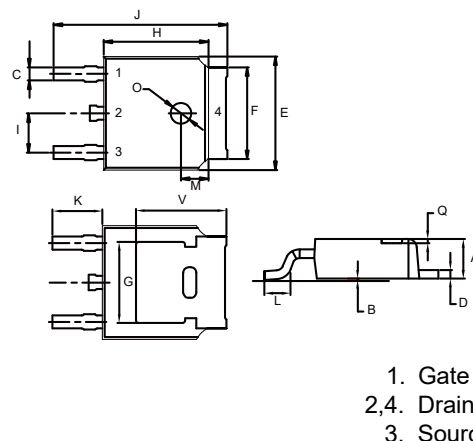
1. Pulse Test: Pulse Width ≤ 300us, Duty cycle ≤ 2%.
2. The power dissipation P_D is based on $T_{J(MAX)}=150^\circ\text{C}$, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
3. $T_J=25^\circ\text{C}$, $V_{DD}=55\text{V}$, $V_G=10\text{V}$, $L=0.5\text{mH}$.

Internal Structure and Marking Code



N-CHANNEL MOSFET

DPAK(TO-252)



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.087	0.094	2.20	2.40	
B	0.000	0.005	0.00	0.13	
C	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
E	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
H	0.236	0.244	6.00	6.20	
I	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
M	0.063		1.60		TYP.
O	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.35		TYP.

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	60			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.5	2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=15A$		5.6	7.2	m Ω
		$V_{GS}=4.5V, I_D=10A$		6.8	8.5	m Ω
Gate Resistance	R_g	f=1MHz, Open drain		2.1		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				90	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=15A$		0.8	1.2	V
Reverse Recovery Time	t_{rr}	$I_S=20A, di_F/dt=100A/\mu s$		27		ns
Reverse Recovery Charge	Q_{rr}			18		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=30V, V_{GS}=0V, f=1MHz$		5170		pF
Output Capacitance	C_{oss}			300		
Reverse Transfer Capacitance	C_{rss}			155		
Total Gate Charge	Q_g	$V_{DS}=30V, V_{GS}=10V, I_D=25A$		102		nC
Gate-Source Charge	Q_{gs}			18.7		
Gate-Drain Charge	Q_{gd}			20		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DD}=30V, I_D=20A$ $R_{GEN}=3\Omega$		12		ns
Turn-On Rise Time	t_r			46		
Turn-Off Delay Time	$t_{d(off)}$			90		
Turn-Off Fall Time	t_f			80		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

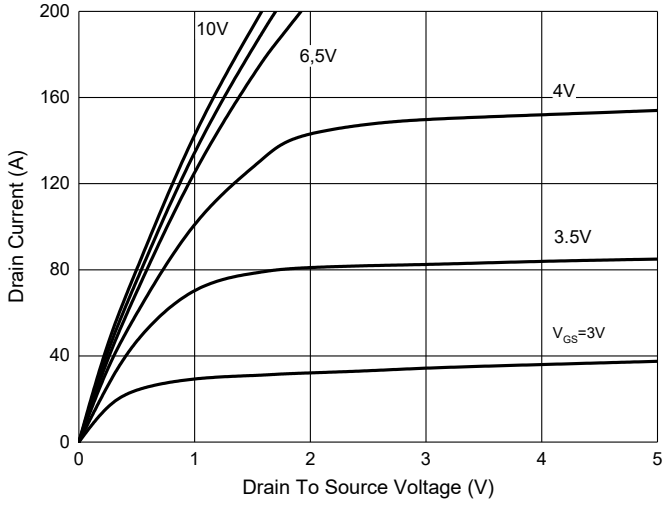


Fig. 2 - Transfer Characteristics

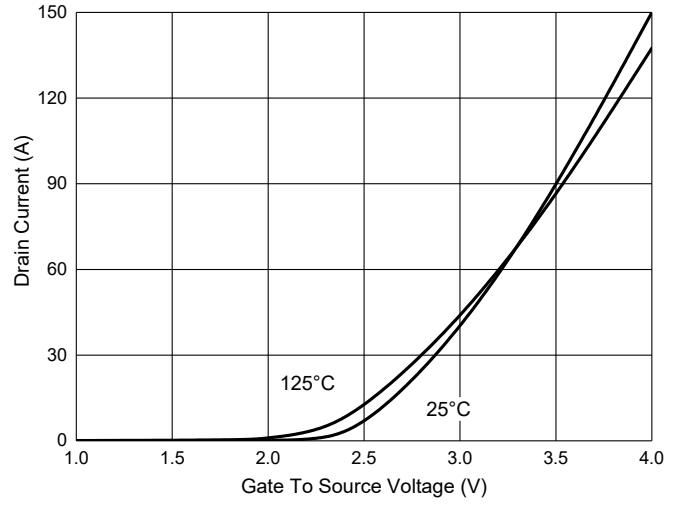


Fig. 3 - $R_{DS(ON)} - I_D$

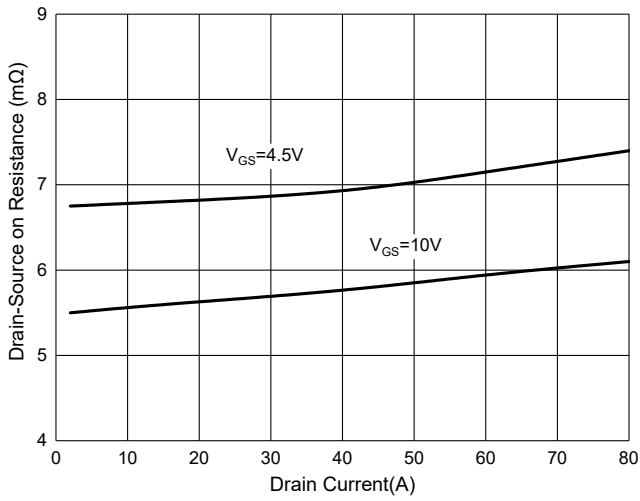


Fig. 4 - Normalized On Resistance Characteristics

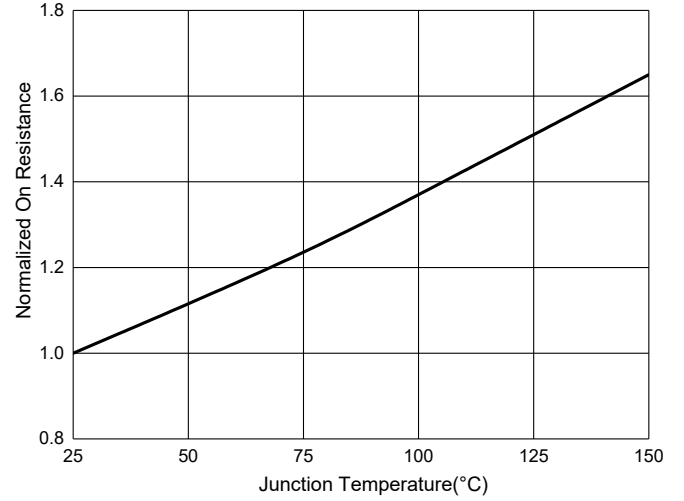


Fig. 5 - Capacitance Characteristics

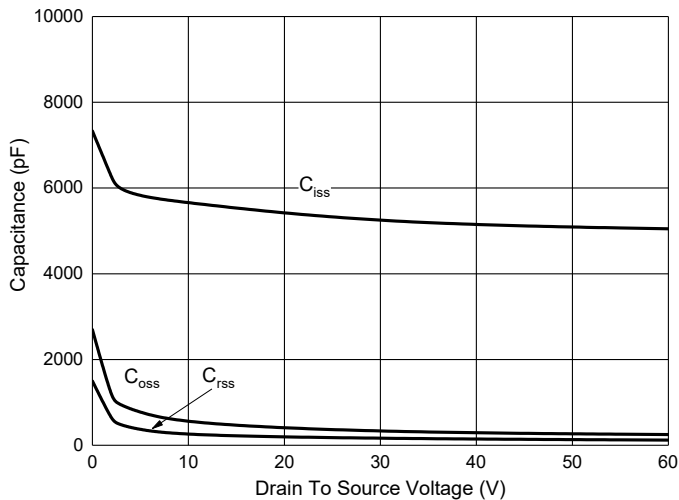
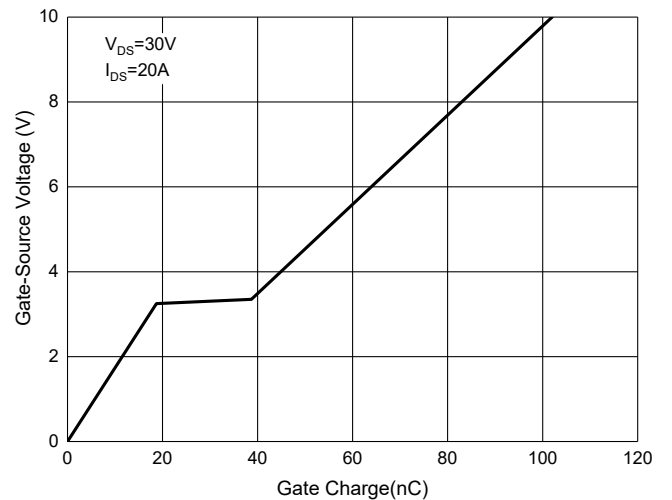
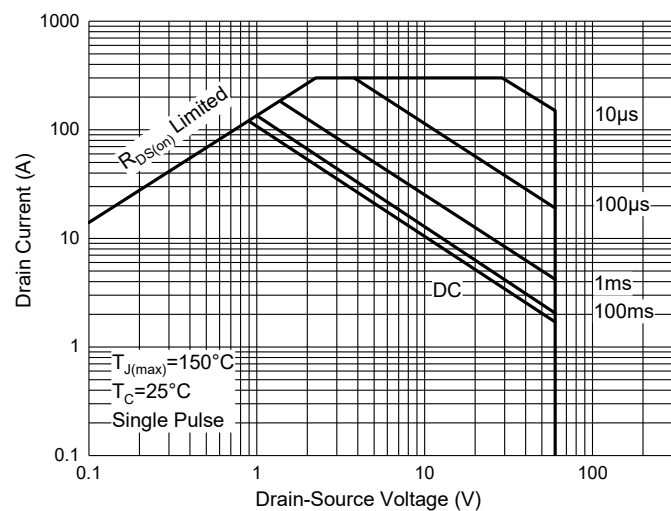


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Safe Operation Area



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

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